

Extremely low capacitance bidirectional ESD protection diode . Rev. 1 — 12 March 2012 **Product data sheet** 

#### 1. **Product profile**

### **1.1 General description**

Extremely low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a leadless ultra small SOD882 (DFN1006-2) Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients. The combination of extremely low capacitance, high ESD maximum rating and ultra small package makes the device ideal for high-speed data line protection.

### 1.2 Features and benefits

- Bidirectional ESD protection of one line ESD protection up to 8 kV
- Extremely low capacitance:  $C_{d} = 0.49 \text{ pF}$
- Low clamping voltage: V<sub>CL</sub> = 18 V
- Ultra low leakage current: I<sub>RM</sub> = 1 nA

### 1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- 10/100/1000 Mbit/s Ethernet
- USB, High-Definition Multimedia Interface (HDMI), FireWire

### 1.4 Quick reference data

- IEC 61000-4-2; level 4 (ESD)
- AEC-Q101 qualified
- Portable electronics
- SIM card protection
- High-speed data lines
- Communication systems

| Table 1.         | Quick reference data                  |                        |   |      |      |    |  |
|------------------|---------------------------------------|------------------------|---|------|------|----|--|
| Symbol           | Parameter Conditions Min Typ Max Unit |                        |   |      |      |    |  |
| Per devic        | e                                     |                        |   |      |      |    |  |
| V <sub>RWM</sub> | reverse standoff voltage              |                        | - | -    | 5.5  | V  |  |
| C <sub>d</sub>   | diode capacitance                     | $f = 1 MHz; V_R = 0 V$ | - | 0.49 | 0.60 | pF |  |



#### Extremely low capacitance bidirectional ESD protection diode

## 2. Pinning information

| Table 2. | Pinning           |                         |                |
|----------|-------------------|-------------------------|----------------|
| Pin      | Description       | Simplified outline      | Graphic symbol |
| 1        | cathode (diode 1) |                         |                |
| 2        | cathode (diode 2) | 1 2                     | 1 2<br>sym045  |
|          |                   | Transparent<br>top view |                |

### 3. Ordering information

| Table 3. Ordering | information |  |         |
|-------------------|-------------|--|---------|
| Type number       | Package     |  |         |
|                   | Name        | Description  | Version |
| PESD5V0X1BCL      | DFN1006-2   | leadless ultra small plastic package; 2 terminals; body 1.0 $\times$ 0.6 $\times$ 0.5 mm | SOD882  |

### 4. Marking

| Table 4. Mar | king codes |              |
|--------------|------------|--------------|
| Type number  |            | Marking code |
| PESD5V0X1BC  | CL         | 11           |

## 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                | Conditions               | Min          | Max  | Unit |
|------------------|--------------------------|--------------------------|--------------|------|------|
| Per device       |                          |                          |              |      |      |
| I <sub>PPM</sub> | rated peak pulse current | t <sub>p</sub> = 8/20 μs | <u>[1]</u> _ | 1.7  | А    |
| T <sub>j</sub>   | junction temperature     |                          | -            | 150  | °C   |
| T <sub>amb</sub> | ambient temperature      |                          | -55          | +150 | °C   |
| T <sub>stg</sub> | storage temperature      |                          | -65          | +150 | °C   |
|                  |                          |                          |              |      |      |

[1] Device stressed with ten non-repetitive current pulses (8/20  $\mu$ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321).

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#### Table 6.ESD maximum ratings

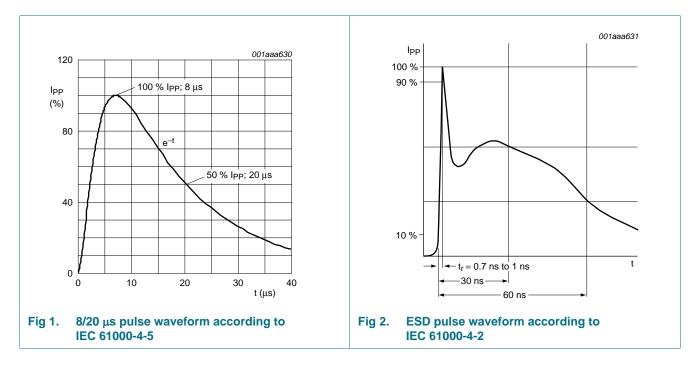
 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

| Parameter                       | Conditions                           | Min  | Мах   | Unit   |
|---------------------------------|--------------------------------------|--|---|--|
| e                               |                                      |  |   |  |
| electrostatic discharge voltage | IEC 61000-4-2<br>(contact discharge) | <u>[1]</u> _   | 8   | kV   |
|                                 | machine model                        | -  | 400   | V  |
|                                 | MIL-STD-883<br>(human body model)    | -  | 10  | kV   |
|                                 | e                                    | electrostatic discharge voltage<br>ielectrostatic discharge voltage<br>(contact discharge)<br>machine model<br>MIL-STD-883 | electrostatic discharge voltage<br>IEC 61000-4-2 [1] -<br>(contact discharge)<br>machine model -<br>MIL-STD-883 - | electrostatic discharge voltage IEC 61000-4-2 [1] - 8<br>(contact discharge) - 400<br>MIL-STD-883 - 10 |

[1] Device stressed with ten non-repetitive ESD pulses.

| Table 7. | ESD s | standards  | compliance      |
|----------|-------|------------|-----------------|
|          |       | , and a do | o o in pilano o |

| Conditions       |
|------------------|
|                  |
| > 8 kV (contact) |
| > 8 kV           |
|                  |



#### Extremely low capacitance bidirectional ESD protection diode

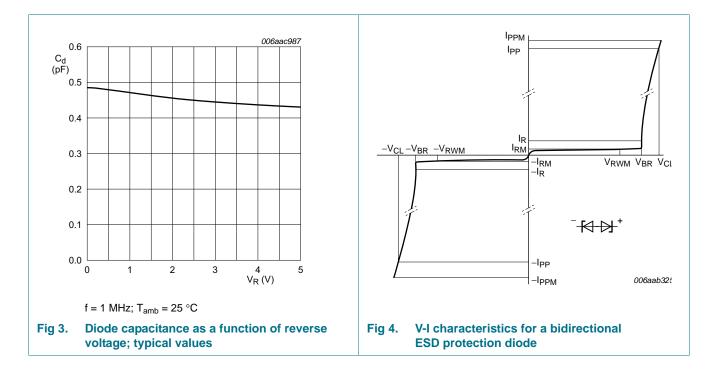
## 6. Characteristics

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

| Tamb = 20 0 unless otherwise specified. |                             |                          |              |      |      |      |  |
|---|-----------------------------|--------------------------|--------------|------|------|------|--|
| Symbol                                  | Parameter                   | Conditions               | Min          | Тур  | Max  | Unit |  |
| Per devi                                | ce                          |                          |              |      |      |      |  |
| V <sub>RWM</sub>                        | reverse standoff<br>voltage |                          | -            | -    | 5.5  | V    |  |
| I <sub>RM</sub>                         | reverse leakage current     | $V_{RWM} = 5.5 V$        | -            | <1   | 10   | nA   |  |
| $V_{BR}$                                | breakdown voltage           | I <sub>R</sub> = 10 mA   | 8.1          | 9.8  | 12.3 | V    |  |
| C <sub>d</sub>                          | diode capacitance           | $f = 1 MHz; V_R = 0 V$   | -            | 0.49 | 0.60 | pF   |  |
| V <sub>CL</sub>                         | clamping voltage            | I <sub>PPM</sub> = 1.7 A | <u>[1]</u> _ | -    | 18   | V    |  |
| r <sub>dyn</sub>                        | dynamic resistance          | I <sub>R</sub> = 10 A    | [2] _        | 0.9  | -    | Ω    |  |
|   |                             |                          |              |      |      |      |  |

[1] Device stressed with 8/20  $\mu$ s exponential decay waveform according to IEC 61000-4-5 and IEC 61643-321.

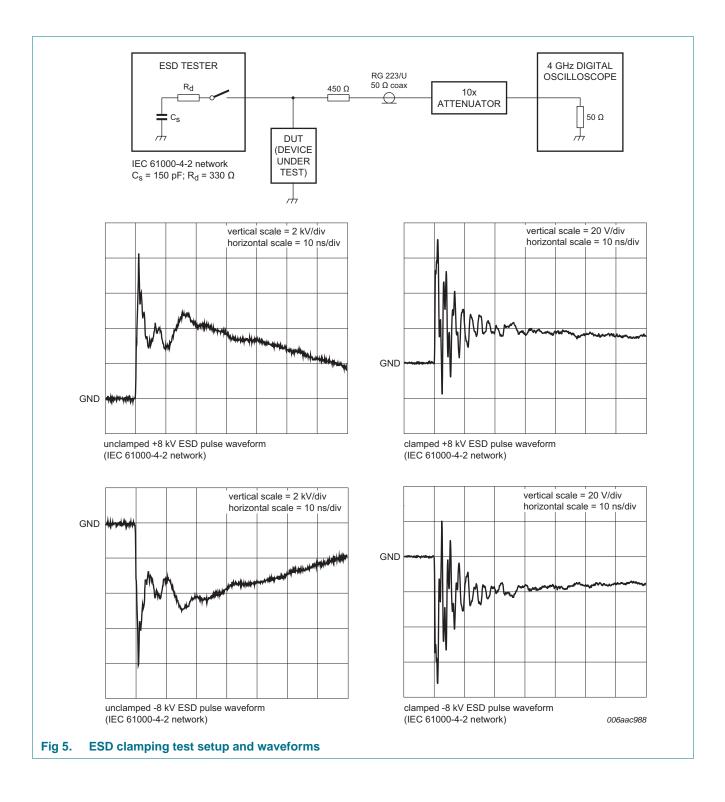
[2] Non-repetitive current pulse, Transmission Line Pulse (TLP)  $t_p$  = 100 ns; square pulse; ANS/IESD STM5-1-2008.



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## PESD5V0X1BCL

#### Extremely low capacitance bidirectional ESD protection diode

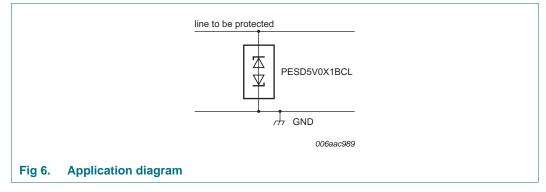


PESD5V0X1BCL Product data sheet

#### Extremely low capacitance bidirectional ESD protection diode

## 7. Application information

PESD5V0X1BCL is designed for the protection of one bidirectional data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both, positive and negative with respect to ground.



#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

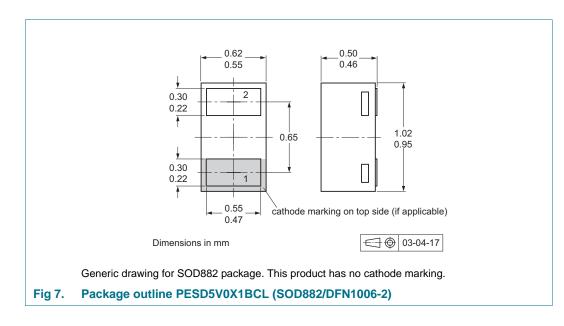
### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Extremely low capacitance bidirectional ESD protection diode

### 9. Package outline



## **10. Packing information**

#### Table 9. Packing methods

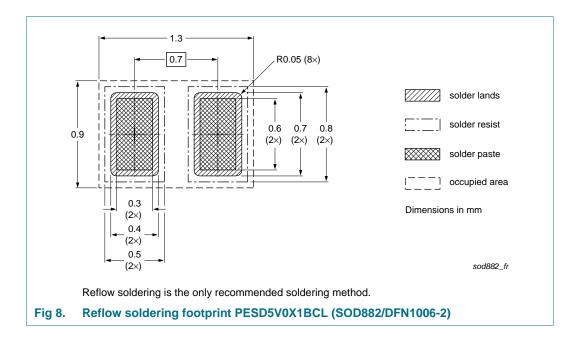
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number  | Package | Description                    | Packing quantity |
|--------------|---------|--------------------------------|------------------|
|              |         |                                | 10000            |
| PESD5V0X1BCL | SOD882  | 2 mm pitch, 8 mm tape and reel | -315             |

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

#### Extremely low capacitance bidirectional ESD protection diode

## **11. Soldering**



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## **12. Revision history**

| Table 10. Revision hist | Fable 10. Revision history |                    |               |            |  |  |  |  |
|-------------------------|----------------------------|--------------------|---------------|------------|--|--|--|--|
| Document ID             | Release date               | Data sheet status  | Change notice | Supersedes |  |  |  |  |
| PESD5V0X1BCL v.1        | 20120312                   | Product data sheet | -             | -          |  |  |  |  |

## 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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